

BSS138P 60 V, 360 mA N-channel Trench MOSFET Rev. 1 – 2 November 2010

Product data sheet

1. Product profile

1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- AEC-Q101 qualified

1.3 Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-------------------|-------------------------------------|---|-------|-----|-----|------|
| V _{DS} | drain-source voltage | $T_{amb} = 25 \ ^{\circ}C$ | - | - | 60 | V |
| V _{GS} | gate-source voltage | $T_{amb} = 25 \ ^{\circ}C$ | - | - | ±20 | V |
| I _D | drain current | T _{amb} = 25 °C; V _{GS} = 10 V | [1] - | - | 360 | mA |
| R _{DSon} | drain-source on-state resistance | T _j = 25 °C; V _{GS} = 10 V; I _D = 300 mA | [2] _ | 0.9 | 1.6 | Ω |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².

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2. Pinning information

| Table 2. | Pinning | | | |
|----------|---------|-------------|--------------------|-------------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | G | gate | | - |
| 2 | S | source | | |
| 3 | D | drain | | G (F) mbb076 S |

3. Ordering information

| Table 3. Ordering information | | | | | |
|-------------------------------|----------|--|---------|--|--|
| Type number | Package | | | | |
| | Name | Description | Version | | |
| BSS138P | TO-236AB | plastic surface-mounted package; 3 leads | SOT23 | | |

4. Marking

| Table 4. Marking codes | |
|--------------------------------|-----------------------------|
| Type number | Marking code ^[1] |
| BSS138P | AN* |

[1] * = placeholder for manufacturing site code

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Parameter | Conditions | Min | Max | Unit |
|----------------------|---|---|---|---|
| drain-source voltage | T _{amb} = 25 °C | - | 60 | V |
| gate-source voltage | T _{amb} = 25 °C | - | ±20 | V |
| drain current | V _{GS} = 10 V | <u>[1]</u> | | |
| | T _{amb} = 25 °C | - | 360 | mA |
| | T _{amb} = 100 °C | - | 230 | mA |
| peak drain current | $\begin{array}{l} T_{amb} = 25 \ ^{\circ}C; \\ single \ pulse; \ t_p \leq 10 \ \mu s \end{array}$ | - | 1.2 | А |
| | drain-source voltage gate-source voltage drain current | $\label{eq:constraint} \begin{array}{ll} \mbox{drain-source voltage} & T_{amb} = 25 \ ^{\circ}C$ \\ \mbox{gate-source voltage} & T_{amb} = 25 \ ^{\circ}C$ \\ \mbox{drain current} & V_{GS} = 10 \ V$ \\ \hline T_{amb} = 25 \ ^{\circ}C$ \\ \hline T_{amb} = 100 \ ^{\circ}C$ \\ \hline T_{amb} = 25 \ ^{\circ}C; \end{array}$ | $\begin{array}{ccc} \text{drain-source voltage} & T_{amb} = 25 \ ^{\circ}\text{C} & - \\ \text{gate-source voltage} & T_{amb} = 25 \ ^{\circ}\text{C} & - \\ \text{drain current} & \frac{V_{GS} = 10 \ \text{V}}{T_{amb} = 25 \ ^{\circ}\text{C}} & - \\ \hline & T_{amb} = 100 \ ^{\circ}\text{C} & - \\ \hline & T_{amb} = 100 \ ^{\circ}\text{C} & - \\ \hline & T_{amb} = 25 \ ^{\circ}\text{C}; & - \\ \end{array}$ | $\begin{array}{c c} drain-source \ voltage \\ gate-source \ voltage \\ drain \ current \\ \end{array} \begin{array}{c} T_{amb} = 25 \ ^{\circ}C & - & 60 \\ T_{amb} = 25 \ ^{\circ}C & - & \pm 20 \\ \end{array}$ $\begin{array}{c} T_{amb} = 25 \ ^{\circ}C & - & \pm 20 \\ \hline T_{amb} = 10 \ ^{\circ}C & - & 360 \\ \hline T_{amb} = 100 \ ^{\circ}C & - & 230 \\ \end{array}$ $\begin{array}{c} peak \ drain \ current \\ \hline T_{amb} = 25 \ ^{\circ}C; & - & 1.2 \\ \end{array}$ |

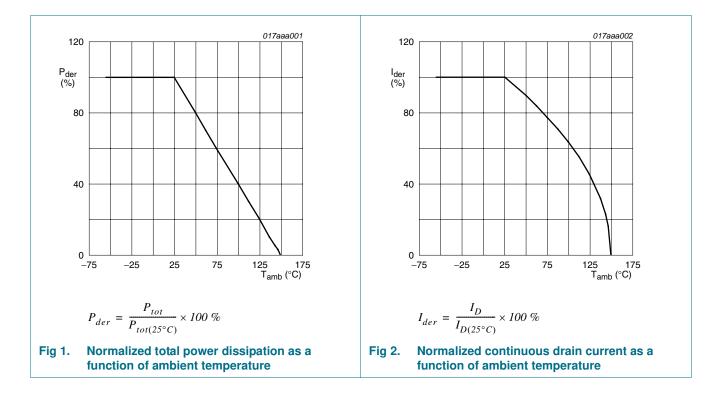
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| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------------------|-------------------------|--|--------------|------|------|
| P _{tot} total power of | total power dissipation | ower dissipation $T_{amb} = 25 \text{ °C}$ | [2] - | 350 | mW |
| | | | [1] - | 420 | mW |
| | | T _{sp} = 25 °C | - | 1140 | mW |
| Tj | junction temperature | | | 150 | °C |
| T _{amb} | ambient temperature | | -55 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Source-d | rain diode | | | | |
| I _S | source current | T _{amb} = 25 °C | <u>[1]</u> - | 360 | mA |

 Table 5.
 Limiting values ...continued

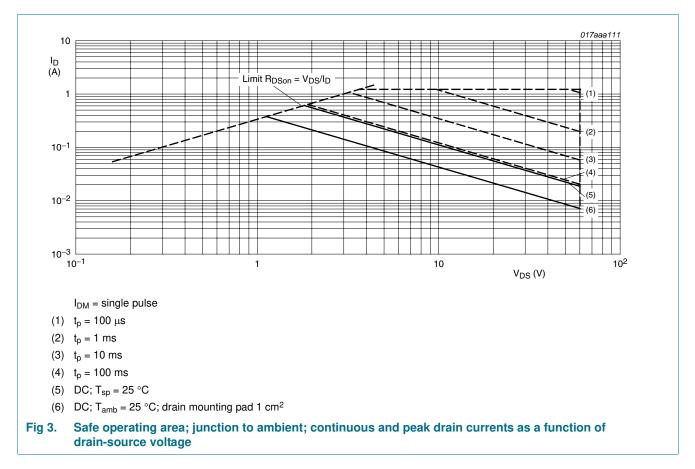
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



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6. Thermal characteristics

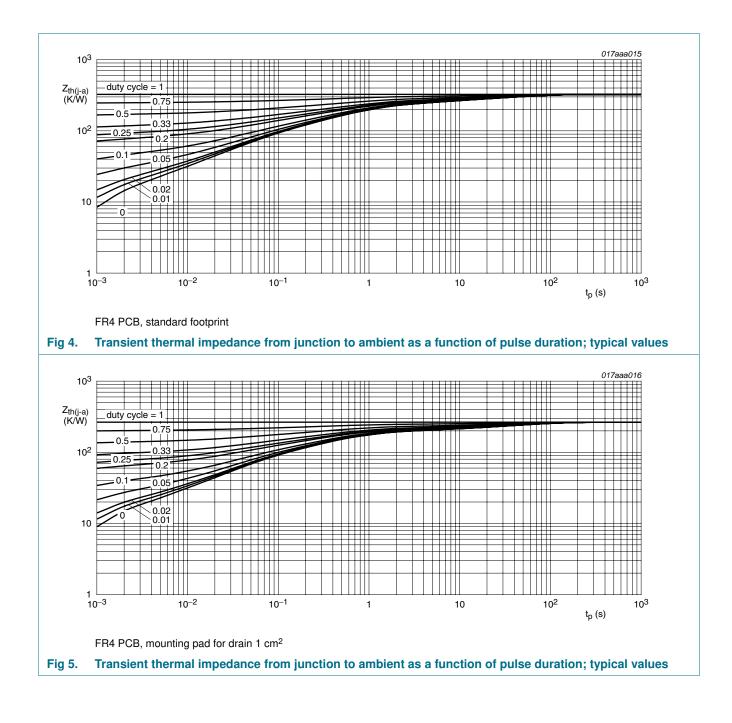
Table 6.Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|-------------|--------------|-----|-----|------|
| $R_{\text{th(j-a)}}$ | thermal resistance from junction to ambient | in free air | <u>[1]</u> - | 310 | 370 | K/W |
| | | | [2] _ | 260 | 300 | K/W |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | - | - | 115 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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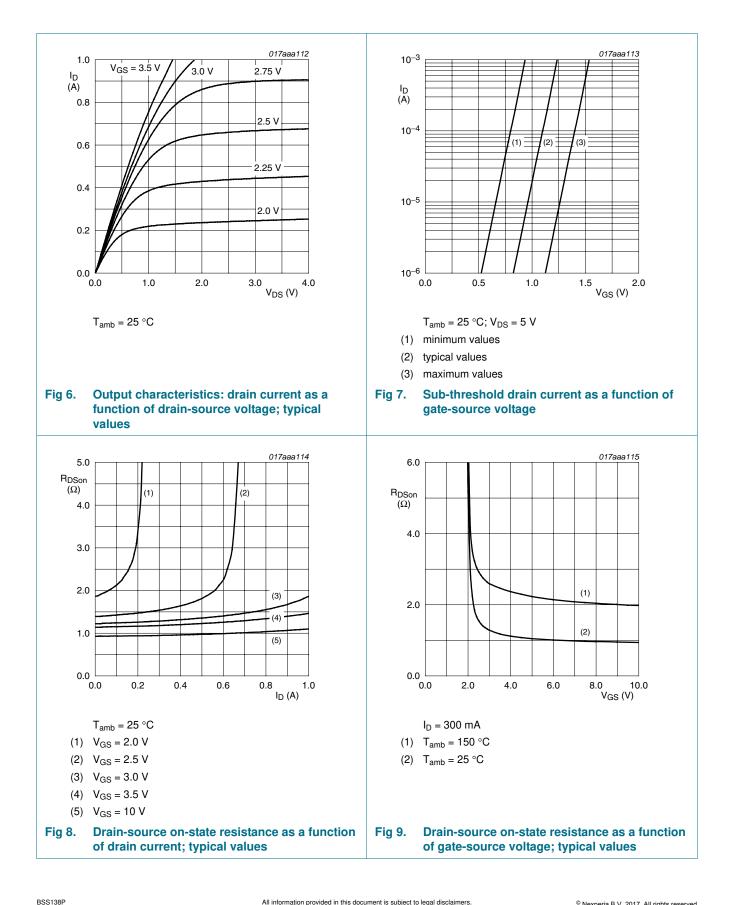
7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-----------------------------------|--|--------------|------|-----|------|
| Static cha | racteristics | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | $I_D = 10 \ \mu\text{A}; \ V_{GS} = 0 \ V$ | 60 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | $I_D = 250 \ \mu\text{A}; \ V_{DS} = V_{GS}$ | 0.9 | 1.2 | 1.5 | V |
| I _{DSS} | drain leakage current | $V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}$ | | | | |
| | | T _j = 25 °C | - | - | 1 | μA |
| | | T _j = 150 °C | - | - | 10 | μA |
| I _{GSS} | gate leakage current | $V_{GS}=\pm 20~V;~V_{DS}=0~V$ | - | - | 100 | nA |
| R _{DSon} | drain-source on-state | | <u>[1]</u> | | | |
| | resistance | $V_{GS} = 5 \text{ V}; I_D = 50 \text{ mA}$ | - | 1 | 2 | Ω |
| | | V_{GS} = 10 V; I _D = 300 mA | - | 0.9 | 1.6 | Ω |
| 9fs | forward transconductance | V_{DS} = 10 V; I _D = 200 mA | <u>[1]</u> _ | 700 | - | mS |
| Dynamic | characteristics | | | | | |
| Q _{G(tot)} | total gate charge | I _D = 300 mA; | - | 0.72 | 0.8 | nC |
| Q _{GS} | gate-source charge | V _{DS} = 30 V; V _{GS} = 4.5 V | - | 0.14 | - | nC |
| Q _{GD} | gate-drain charge | $V_{GS} = 4.5 V$ | - | 0.24 | - | nC |
| C _{iss} | input capacitance | $V_{GS} = 0 V; V_{DS} = 10 V;$ | - | 38 | 50 | pF |
| C _{oss} | output capacitance | f = 1 MHz | - | 7 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 4 | - | pF |
| t _{d(on)} | turn-on delay time | V _{DS} = 50 V; | - | 2 | 6 | ns |
| t _r | rise time | $R_{L} = 250 \Omega;$ | - | 3 | - | ns |
| t _{d(off)} | turn-off delay time | – V _{GS} = 10 V; R _G = 6 Ω | - | 9 | 20 | ns |
| t _f | fall time | _ ~ | - | 4 | - | ns |
| Source-di | ain diode | | | | | |
| V _{SD} | source-drain voltage | I _S = 115 mA; V _{GS} = 0 V | 0.47 | 0.75 | 1.1 | V |

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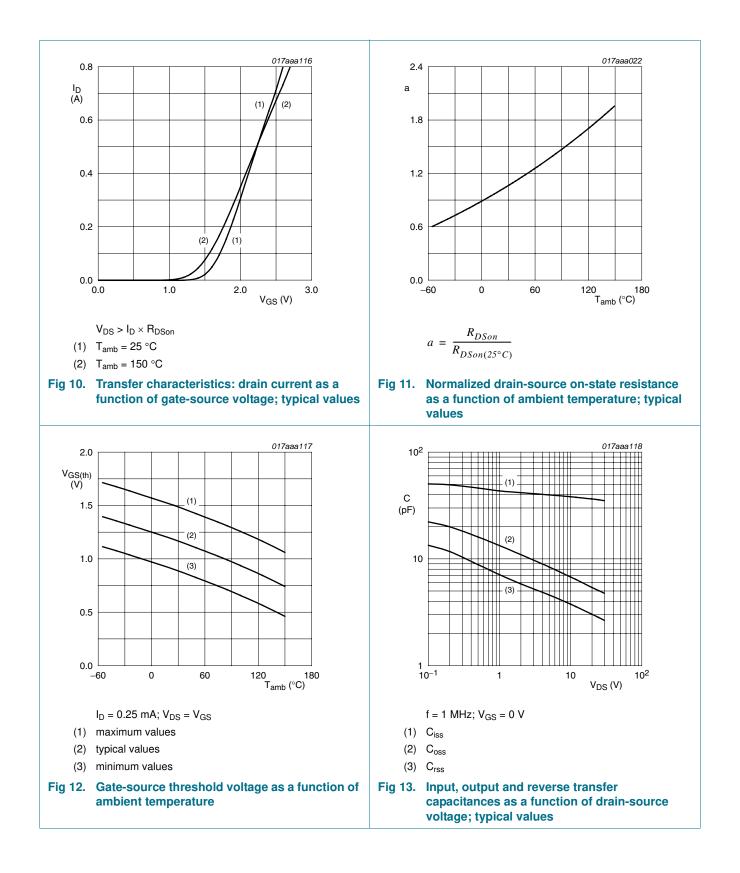
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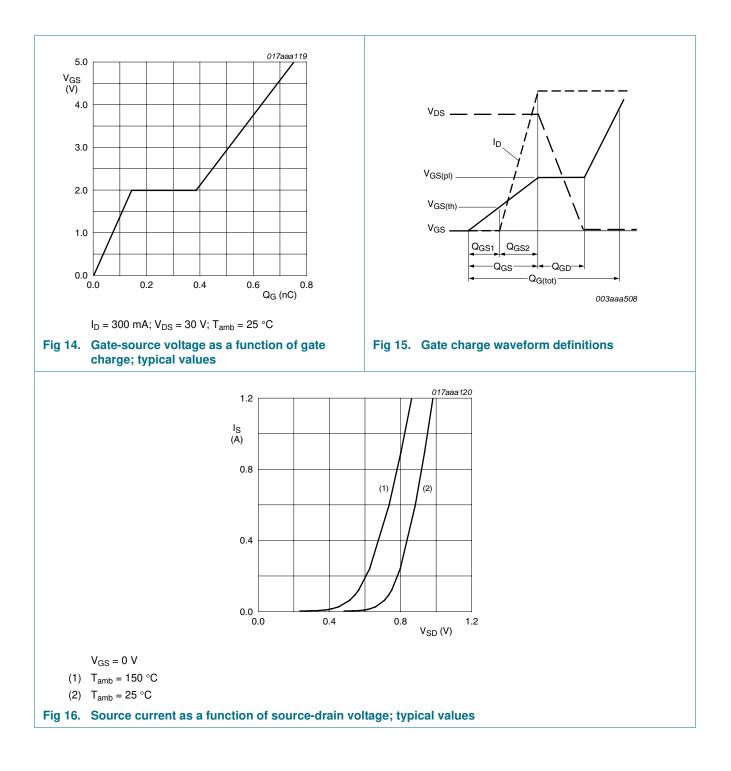
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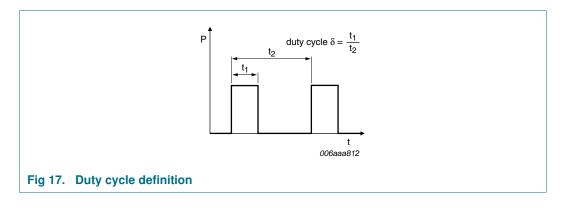


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8. Test information



8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline

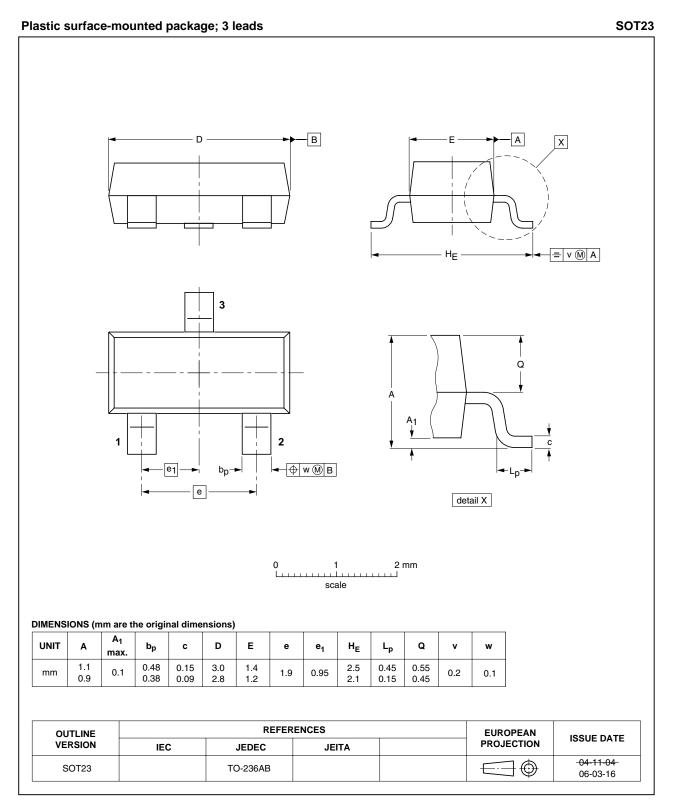
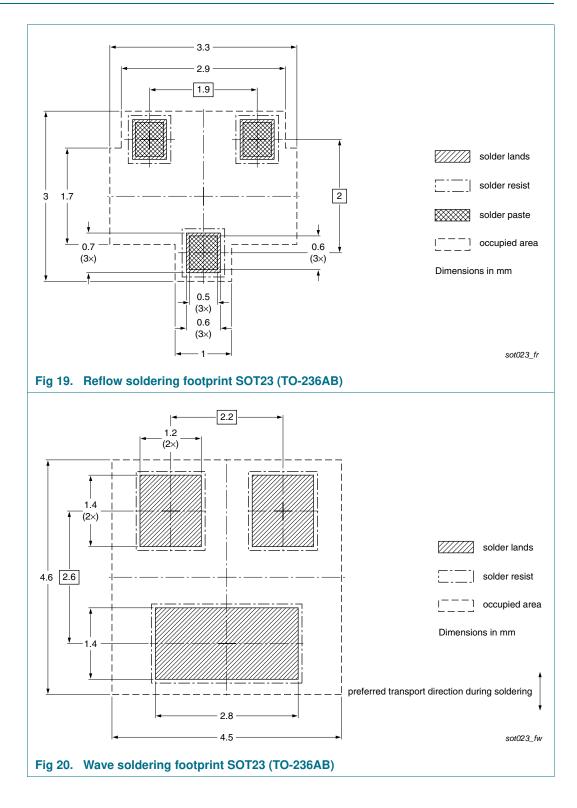


Fig 18. Package outline SOT23 (TO-236AB)

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10. Soldering



11. Revision history

| Table 8. Revis | ion history | | | |
|----------------|--------------|--------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| BSS138P v.1 | 20101102 | Product data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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[2] The term 'short data sheet' is explained in section "Definitions".

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